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PTO/SB/08A (08-00)
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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>			Complete if Known		
			Application Number		
			Filing Date		
			First Named Inventor		
			Group Art Unit		
			Examiner Name		
Sheet	1	of	2	Attorney Docket Number	
				MXIC 1553-3	

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
<div style="display: inline-block; transform: rotate(-45deg); font-size: small;"> [Signature] [Signature] </div>	A1	4,442,507		Roesner	4/10/1984	
	A2	5,536,968		Crafts et al.	7/16/1996	
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	A4					
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FOREIGN PATENT DOCUMENTS								
Examiner Initials*	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Office ³	Number ⁴	Kind Code ⁵ (if known)				
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Examiner Signature		Date Considered	1/18/05
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¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

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Substitute for form 1449B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>		Compleat If Known			
		Application Number			
		Filing Date	15 August 2003		
		First Named Inventor	Chih C. YEH et al.		
		Group Art Unit			
		Examiner Name			
Sheet	2	of	2	Attorney Docket Number	MXIC 1553-3

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
DJO	C1	C. de GRAAF et al., "A Novel High-Density Low-Cost Diode Programmable Read Only Memory" Philips Research Labs., Prof. Holstlaan 4, 5656AA Eindhoven, The Netherlands, 1996 IEDM, pps. 189-192.	
	C2	M. JELINEK et al., "Hybrid PLD Technique for Nitrogen Rich CNx Layers", Lasers and Electro-Optics Europe, 2000. Conf. Digest. 2000 Conf. on, 10-15 Sept 2000, 1 page.	
	C3	B. LINDER et al., "Growth and Scaling of Oxide Conduction After Breakdown", 41st Annual Int'l Reliability Physics Symposium, Dallas, TX, 2003, pp. 402-405.	
	C4	S. ROSSNAGEL et al., "From PVD to CVD to ALD for Interconnects and Related Applications", Interconnect Technology Conf., 2001. Proceedings of the IEEE 2001 Int'l, 4-6 June 2001, pp. 3-5.	
DJO	C5	X.W WANG et al., "Ultra-Thin Silicon Nitride Films on Si by Jet Vapor Deposition", VLSI Technology, Systems and Applications, 1995, Proceedings of Technical Papers, 1995 International Symposium on, 31 May-2 June 1995, pp. 49-52.	

Examiner Signature		Date Considered	1/18/05
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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)		Complete if Known	
		Application Number	10/642,249
		Filing Date	15 August 2003
		First Named Inventor	Chih C. Yeh et al.
		Art Unit	Unassigned
		Examiner Name	Unassigned
Sheet 2	of 2	Attorney Docket Number	MXIC 1553-3

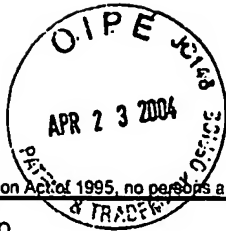
NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
DHO	C1	Takuji Hosoi et al. "A New Model of Time Evolution of Gate Leakage Current After Soft Breakdown in Ultra-Thin Gate Oxides" IEEE February 2002 pages 155-158.	
DHO	C2	Tahui Wang et al. "Negative Substrate Bias Enhanced Breakdown Hardness in Ultra-Thin Oxide pMOSFETs" IEEE 41st Annual International Reliability Physics Symposium, Dallas, Texas August 2003 pages 437-441.	

Examiner Signature	<i>Daniel W. Owen</i>	Date Considered	1/18/05
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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

Complete if Known

Application Number	10/642,249
Filing Date	15 August 2003
First Named Inventor	Chih C. Yeh et al.
Art Unit	2818
Examiner Name	Unassigned
Attorney Docket Number	MXIC 1553-3

Sheet 1 of 1

U. S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
D10	A1	US- 5,093,711 A1	03-03-1992	Kazuki Hirakawa	
	A2	US- 5,350,710 A	09-27-1994	Hong et al.	
	A3	US- 6,432,782 B1	08-13-2002	Lung et al.	
	A4	US- 6,534,841 B1	03-18-2003	Van Brocklin et al.	
	A5	US- 6,541,312 B2	04-01-2003	Cleeves et al.	
	A6	US- 6,555,844 B1	04-29-2003	Lin et al.	
	A7	US- 6,617,206 B1	09-09-2003	Sandu et al.	
	A8	US- 6,618,295 B2	09-09-2003	Scheuerlein	
	A9	US- 6,677,220 B2	01-13-2004	Van Brocklin et al.	
	A10	US- 6,703,652 B2	03-09-2004	Van Brocklin et al.	
	A11	US- 6,704,235 B2	03-09-2004	Knall et al.	
D10	A12	US- 2003/0080370 A1	05-01-2003	Harari et al.	
	A13	US- 2004/0031853 A1	02-19-2004	Peng	
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FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages Or Relevant Figures Appear	T ⁴
		Country Code ³ Number ⁴ Kind Code ⁵ (if known)				

Examiner
Signature*Douglas K. Owe*Date
Considered

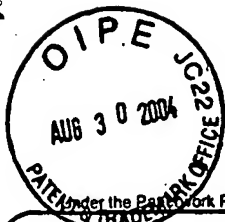
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STATEMENT BY APPLICANT**

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Sheet 1

of 2

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Application Number	10/642,249
Filing Date	15 August 2003
First Named Inventor	Chih C. Yeh et al.
Art Unit	2818
Examiner Name	Unassigned
Attorney Docket Number	MXIC 1553-3

U. S. PATENT DOCUMENTS

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		Number-Kind Code ² (if known)			
210	A1	US- 6,650,143	11-18-2003	Peng	
	A2	US- 6,667,902	12-23-2003	Peng	
	A3	US- 6,671,040	12-30-2003	Fong et al.	
	A4	US- 6,700,151	03-02-2004	Peng	
	A5	US- 2002/0094611	07-17-2002	Wu et al.	
	A6	US- 2004/0008538	01-15-2004	Peng	
	A7	US- 2004/0047218	03-11-2004	Peng	
	A8	US- 2004/0106251	06-03-2004	Forbes et al.	
	A9	US- 2004/0129995	07-08-2004	Yeo et al.	
	A10	US- 2004/0137688	07-15-2004	Chang et al.	
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		Country Code ³ Number ⁴ Kind Code ⁵ (if known)				

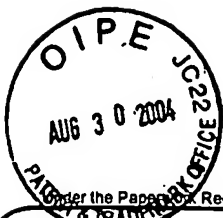
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Examiner Name	Unassigned
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Sheet 2 of 2

NON PATENT LITERATURE DOCUMENTS

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Dkg	C1	Stathis, J.H., "Reliability Limits for the Gate Insulator in CMOS Technology" IBM. J. Res. & Dev., Vol. 46, No. 2/3, March/May 2002, 265-286	
	C2	Miranda, Enrique, et al. "Analytic Modeling of Leakage Current Through Multiple Breakdown Paths in SiO ₂ Films" IEEE 39th Annual IRPS 2001, 367-379	
	C3	Wu, E.Y. et al., "Voltage-Dependent Voltage-Acceleration of Oxide Breakdown for Ultra-Thin Oxides" Electron Devices Meeting, 2000, IEDM Technical Digest International, 10-13 December 2000, 541-544	
	C4	Sune, Jordi et al. "Post Soft Breakdown Conduction in SiO ₂ Gate Oxides" Electron Devices Meeting, 2000 IEDM Technical Digest International, 10-13 Dec. 2000 533-536	
	C5	Rasras, Mahmoud et al. "Substrate Hole Current Origin After Oxide Breakdown" Electron Devices Meeting, 2000 IEDM Technical Digest International, 10-13 Dec. 2000, 537-540	
	C6	Lombardo, S., et al. "Softening of Breakdown in Ultra-Thin Gate Oxide nMOSFETs at Low Inversion Layer Density" Reliability Physics Symposium 2001, Proceedings 39th Annual 2001 IEEE International, 30 April, 3 May 2001, 163-167	
	C7	Monsieur, F., et al. "A Thorough Investigation of Progressive Breakdown in Ultra-Thin Oxides Physical Understanding and Application for Industrial Reliability Assessment", Reliability Physics Symposium Proceedings 2002, 40th Annual 7-11 April 2000, 45-54	
Dkg	C8	Suehle, J. "Ultra-Thin Gate Oxide Reliability and Implications for Qualification, Design and Use in Ionizing Radiation Environments" NASA Microelectronics Reliability and Qualification Workshop, Manhattan Beach Marriott, Manhattan Beach, CA 12/3/02 30 pgs	

Examiner Signature	<i>Donald K. Omer</i>	Date Considered	1/18/05
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